

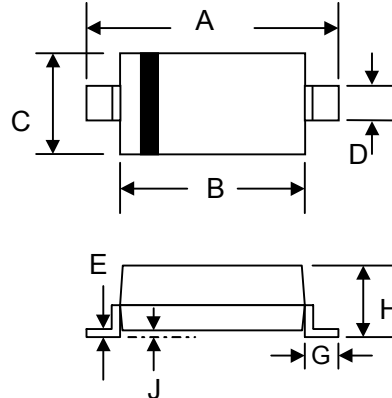


# 1N4148W / BAV16W

## SURFACE MOUNT FAST SWITCHING DIODE

### Features

- High Conductance
- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Application
- Plastic Material – UL Recognition Flammability Classification 94V-0



SOD-123		
Dim	Min	Max
A	3.6	3.9
B	2.5	2.8
C	1.4	1.8
D	0.5	0.7
E	—	0.2
G	0.4	—
H	0.95	1.35
J	—	0.12
All Dimensions in mm		

### Mechanical Data

- Case: SOD-123, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.01 grams (approx.)



### Maximum Ratings @ $T_A=25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	$V_{RM}$	100	V
Peak Repetitive Reverse Voltage	$V_{RRM}$	75	V
Working Peak Reverse Voltage	$V_{RWM}$		
DC Blocking Voltage	$V_R$		
RMS Reverse Voltage	$V_{R(RMS)}$	53	V
Forward Continuous Current (Note 1)	$I_{FM}$	300	mA
Average Rectified Output Current (Note 1)	$I_O$	150	mA
Non-Repetitive Peak Forward Surge Current	$I_{FSM}$	@ $t = 1.0\mu\text{s}$ 2.0	A
		@ $t = 1.0\text{s}$ 1.0	
Power Dissipation (Note 1)	$P_d$	410	mW
Typical Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{\theta JA}$	315	K/W
Operating and Storage Temperature Range	$T_j, T_{STG}$	-65 to +150	$^\circ\text{C}$

### Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Forward Voltage Drop	$V_{FM}$	1.0	V
Peak Reverse Leakage Current	$I_{RM}$	@ $V_R = 20\text{V}$ 25	nA
		@ $V_R = 75\text{V}$ 5.0	$\mu\text{A}$
Typical Junction Capacitance ( $V_R = 0\text{V DC}, f = 1.0\text{MHz}$ )	$C_j$	2.0	pF
Reverse Recovery Time (Note 2)	$t_{rr}$	4.0	nS

- Note: 1. Valid provided that terminals are kept at ambient temperature.  
2. Measured with  $I_F = I_R = 10\text{mA}$ ,  $I_{RR} = 0.1 \times I_R$ ,  $R_L = 100\Omega$ .



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## RATINGS AND CHARACTERISTIC CURVES

FIG.1- FORWARD CHARACTERISTICS

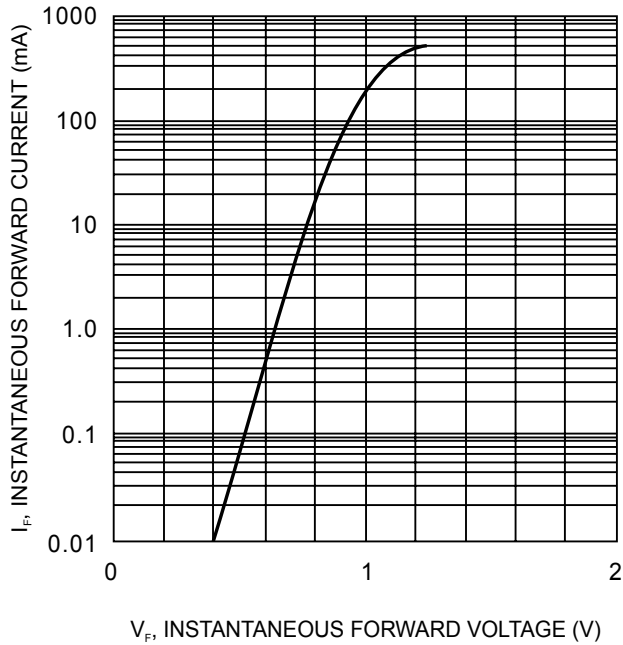


FIG.2- LEAKAGE CURRENT VS JUNCTION TEMPERATURE

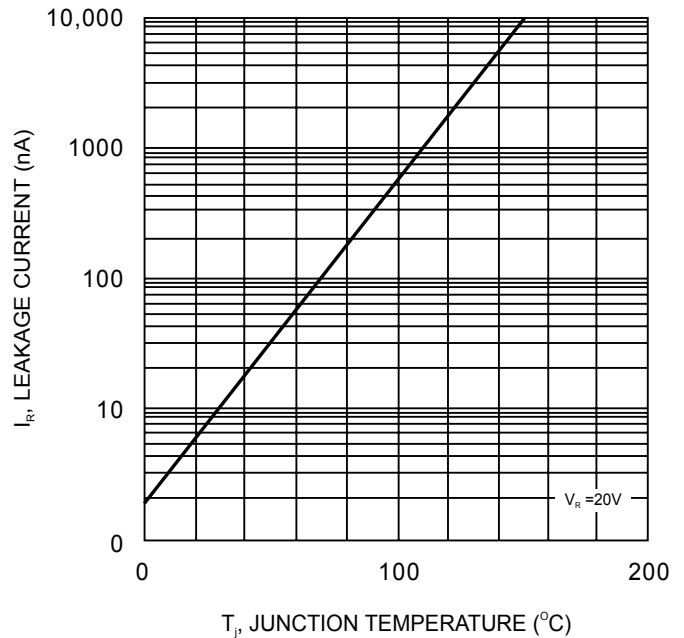


FIG.3- ADMISSIBLE POWER DISSIPATION VS AMBIENT TEMPERATURE

